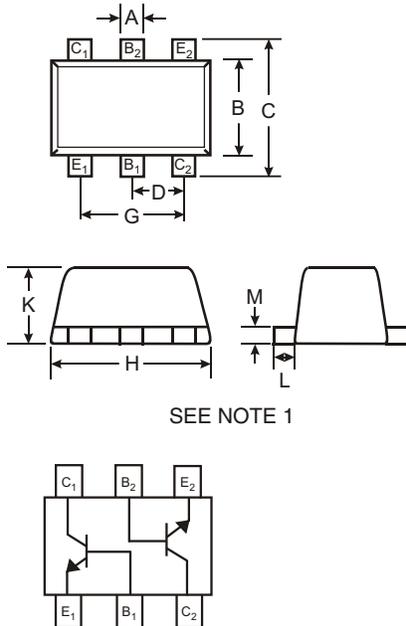


Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 4)**
- "Green Device" (Note 5)**

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking (See Page 2): APK
- Ordering Information: See Below
- Date Code Information: See Page 2
- Weight: 0.003 grams (approximate)



| SOT-563 | | | |
|----------------------|------|------|------|
| Dim | Min | Max | Typ |
| A | 0.15 | 0.30 | 0.25 |
| B | 1.10 | 1.25 | 1.20 |
| C | 1.55 | 1.70 | 1.60 |
| D | 0.50 | | |
| G | 0.90 | 1.10 | 1.00 |
| H | 1.50 | 1.70 | 1.60 |
| K | 0.56 | 0.60 | 0.60 |
| L | 0.10 | 0.30 | 0.20 |
| M | 0.10 | 0.18 | |
| All Dimensions in mm | | | |

Maximum Ratings @ T_A = 25 C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Collector-Base Voltage | V _{CBO} | 60 | V |
| Collector-Emitter Voltage | V _{CEO} | 40 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current - Continuous | I _C | 200 | mA |
| Power Dissipation (Note 2) | P _d | 200 | mW |
| Thermal Resistance, Junction to Ambient | R _{JA} | 625 | C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | C |

Ordering Information (Note 3)

| Device | Packaging | Shipping |
|--------------|-----------|------------------|
| MMDT3904VC-7 | SOT-563 | 3000/Tape & Reel |

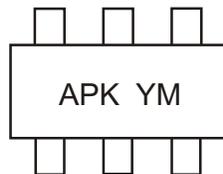
- Notes:
1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
 2. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
 4. No purposefully added lead.
 5. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

Electrical Characteristics @ T_A = 25 °C unless otherwise specified

| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|--------------------------------------|----------------------|-----------------------------|--------------|--------------------|--|
| OFF CHARACTERISTICS (Note 6) | | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | 60 | | V | I _C = 10 A, I _E = 0 |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | 40 | | V | I _C = 1.0mA, I _B = 0 |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | 5.0 | | V | I _E = 10 A, I _C = 0 |
| Collector Cutoff Current | I _{CEX} | | 50 | nA | V _{CE} = 30V, V _{EB(OFF)} = 3.0V |
| Base Cutoff Current | I _{BL} | | 50 | nA | V _{CE} = 30V, V _{EB(OFF)} = 3.0V |
| ON CHARACTERISTICS (Note 6) | | | | | |
| DC Current Gain | h _{FE} | 40 70 100 60 30 | 300 | | I _C = 100μA, V _{CE} = 1.0V I _C = 1.0mA, V _{CE} = 1.0V I _C = 10mA, V _{CE} = 1.0V I _C = 50mA, V _{CE} = 1.0V I _C = 100mA, V _{CE} = 1.0V |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | | 0.20 0.30 | V | I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA |
| Base-Emitter Saturation Voltage | V _{BE(SAT)} | 0.65 | 0.85 0.95 | V | I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA |
| SMALL SIGNAL CHARACTERISTICS | | | | | |
| Output Capacitance | C _{obo} | | 4.0 | pF | V _{CB} = 5.0V, f = 1.0MHz, I _E = 0 |
| Input Capacitance | C _{ibo} | | 8.0 | pF | V _{EB} = 0.5V, f = 1.0MHz, I _C = 0 |
| Input Impedance | h _{ie} | 1.0 | 10 | k | V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz |
| Voltage Feedback Ratio | h _{re} | 0.5 | 8.0 | x 10 ⁻⁴ | |
| Small Signal Current Gain | h _{fe} | 100 | 400 | | |
| Output Admittance | h _{oe} | 1.0 | 40 | S | |
| Current Gain-Bandwidth Product | f _T | 300 | | MHz | |
| Noise Figure | NF | | 5.0 | dB | V _{CE} = 5.0V, I _C = 100 A, R _S = 1.0k f = 1.0kHz |
| SWITCHING CHARACTERISTICS | | | | | |
| Delay Time | t _d | | 35 | ns | V _{CC} = 3.0V, I _C = 10mA, V _{BE(off)} = - 0.5V, I _{B1} = 1.0mA |
| Rise Time | t _r | | 35 | ns | |
| Storage Time | t _s | | 200 | ns | V _{CC} = 3.0V, I _C = 10mA, I _{B1} = I _{B2} = 1.0mA |
| Fall Time | t _f | | 50 | ns | |

Notes: 6. Short duration test pulse used to minimize self-heating.

Marking Information



APK = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: R = 2004
 M = Month ex: 9 = September

Date Code Key

| Year | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
|------|------|------|------|------|------|------|------|------|
| Code | S | T | U | V | W | X | Y | Z |

| Month | Jan | Feb | March | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

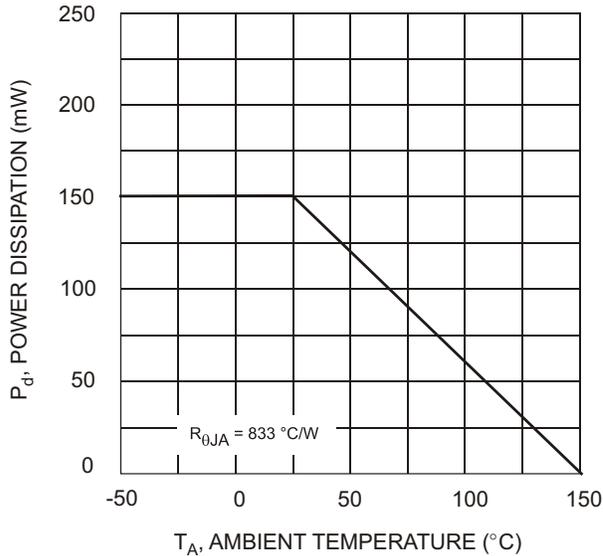


Fig. 1, Derating Curve - Total

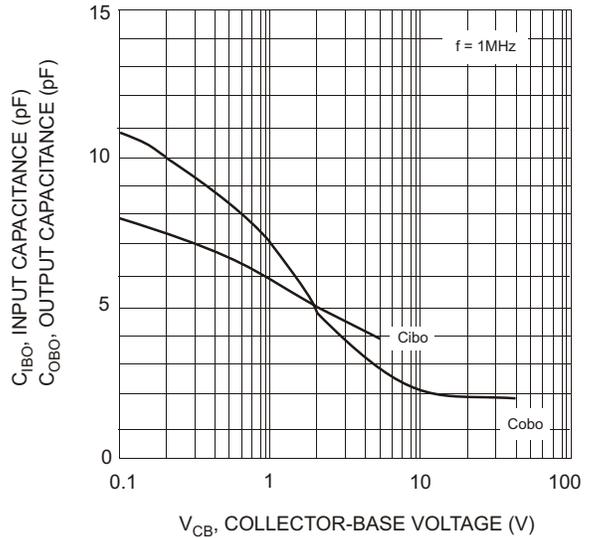


Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage

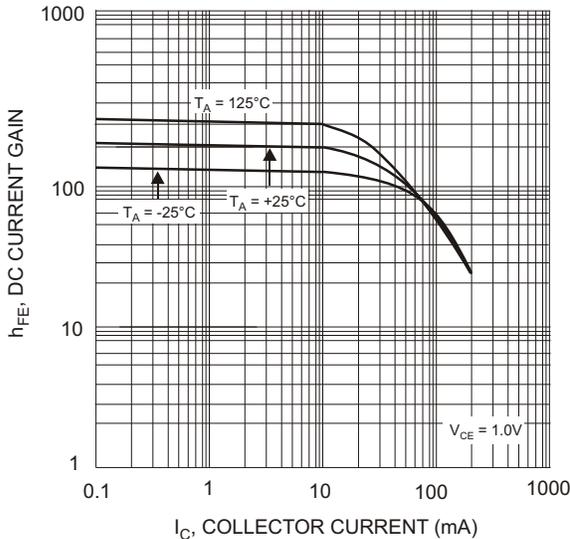


Fig. 3, Typical DC Current Gain vs. Collector Current

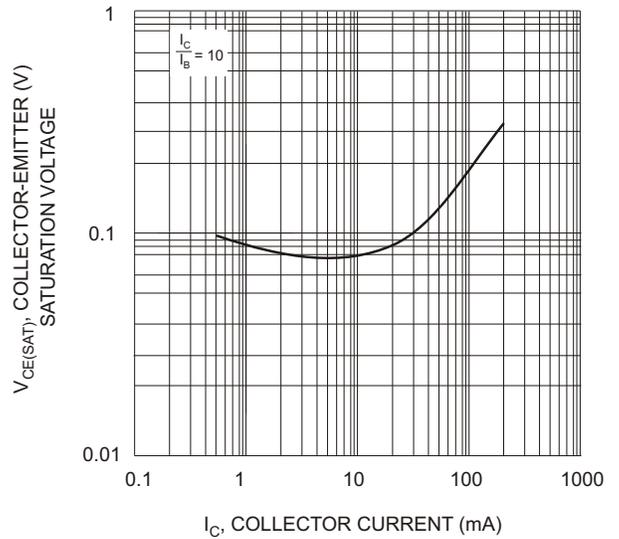


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current

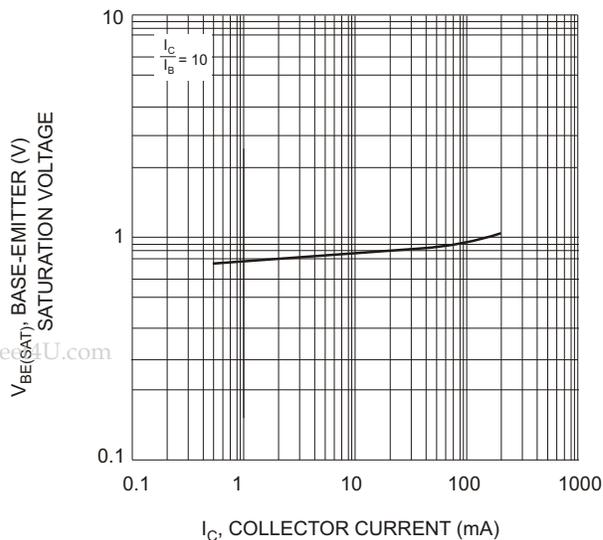


Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current

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